- **Controlled Baseline**
  - **One Assembly/Test Site, One Fabrication Site**
- **Extended Temperature Performance of –40°C to 105°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree†**
- **Supports Mixed-Mode Voltage Operation on All Ports**
- **Fast Switching**

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- **High On-Off Output-Voltage Ratio**
- **Low Crosstalk Between Switches**
- **Extremely Low Input Current**
- **ESD Protection Exceeds JESD 22**
  - **2000-V Human-Body Model (A114-A)**
  - **200-V Machine Model (A115-A)**
  - **1000-V Charged-Device Model (C101)**

D OR PW PACKAGE
(TOP VIEW)

2Y0	1	16	V_{CC}
2Y2	2	15	1Y2
2-COM	3	14	1Y1
2Y3	4	13	1-COM
2Y1	5	12	1Y0
INH	6	11	1Y3
GND	7	10	A
GND	8	9	B
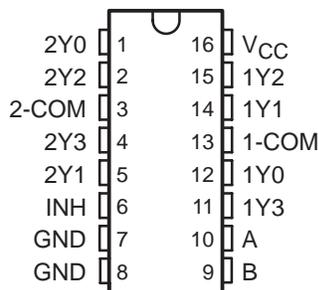
description/ordering information

This dual 4-channel CMOS analog multiplexer/demultiplexer is designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV4052A handles both analog and digital signals. Each channel permits signals with amplitudes up to 5.5 V (peak) to be transmitted in either direction.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

T_A	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40ºC to 105ºC	SOIC – D	Tape and reel	SN74LV4052ATDREP	LV4052ATEP
	TSSOP – PW	Tape and reel	SN74LV4052ATPWREP	L4052EP

‡ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INPUTS			ON CHANNEL
INH	B	A	
L	L	L	1Y0, 2Y0
L	L	H	1Y1, 2Y1
L	H	L	1Y2, 2Y2
L	H	H	1Y3, 2Y3
H	X	X	None

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TEXAS INSTRUMENTS

logic diagram (positive logic)
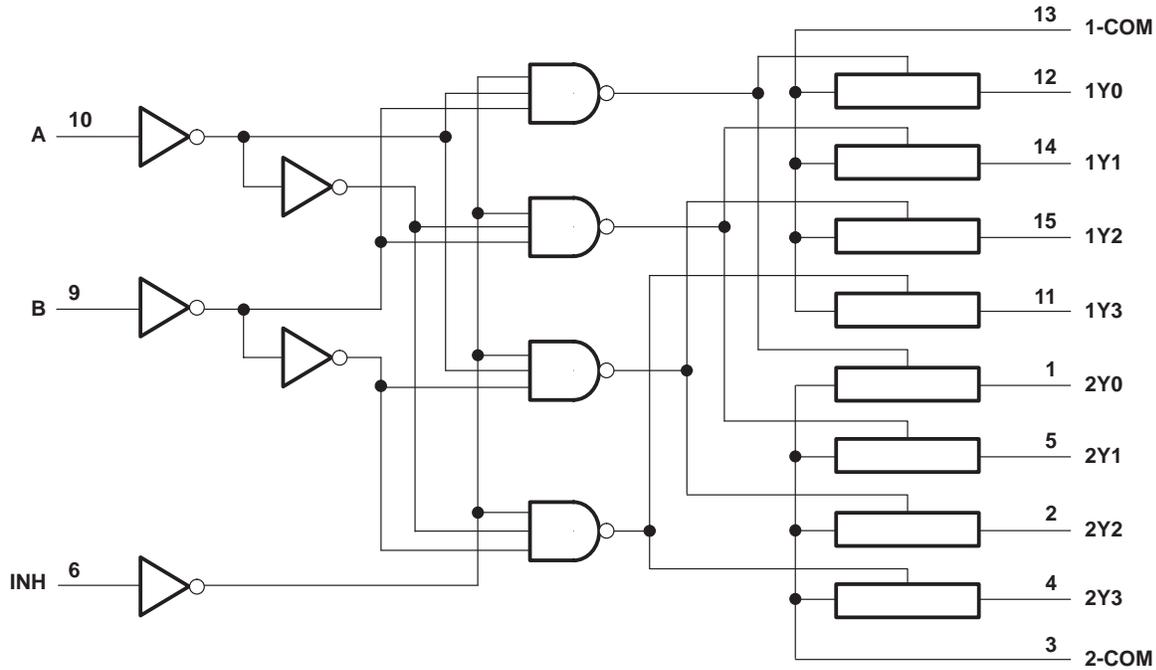
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . −0.5 V to 7.0 V

Input voltage range, V_I (see Note 1) . . . . −0.5 V to 7.0 V

Switch I/O voltage range, V_{IO} (see Notes 1 and 2) . . . . −0.5 V to V_{CC} + 0.5 V

Input clamp current, I_{IK} (V_I < 0) . . . . −20 mA

I/O diode current, I_{IOK} (V_{IO} < 0) . . . . −50 mA

Switch through current, I_T (V_{IO} = 0 to V_{CC}) . . . . ±25 mA

Continuous current through V_{CC} or GND . . . . ±50 mA

Package thermal impedance, θ_{JA} (see Note 3): D package . . . . 73°C/W

PW package . . . . 108°C/W

Storage temperature range, T_{stg} . . . . −65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2†	5.5	V
V_{IH}	High-level input voltage, control inputs	V_{CC} = 2 V	1.5		V
		V_{CC} = 2.3 V to 2.7 V	$V_{CC} \times 0.7$		
		V_{CC} = 3 V to 3.6 V	$V_{CC} \times 0.7$		
		V_{CC} = 4.5 V to 5.5 V	$V_{CC} \times 0.7$		
V_{IL}	Low-level input voltage, control inputs	V_{CC} = 2 V		0.5	V
		V_{CC} = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	
		V_{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$	
		V_{CC} = 4.5 V to 5.5 V		$V_{CC} \times 0.3$	
V_I	Control input voltage		0	5.5	V
V_{IO}	Input/output voltage		0	V_{CC}	V
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 2.3 V to 2.7 V		200	ns/V
		V_{CC} = 3 V to 3.6 V		100	
		V_{CC} = 4.5 V to 5.5 V		20	
T_A	Operating free-air temperature		–40	105	°C

† With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
r_{on}	On-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, $V_{INH} = V_{IL}$, (see Figure 1)	2.3 V		225	Ω
			3 V		190	
			4.5 V		100	
$r_{on(p)}$	Peak on-state resistance	I_T = 2 mA, V_I = V_{CC} to GND, $V_{INH} = V_{IL}$	2.3 V		600	Ω
			3 V		225	
			4.5 V		125	
Δr_{on}	Difference in on-state resistance between switches	I_T = 2 mA, V_I = V_{CC} to GND, $V_{INH} = V_{IL}$	2.3 V		40	Ω
			3 V		30	
			4.5 V		20	
I_I	Control input current	V_I = 5.5 V or GND	0 to 5.5 V		±1	µA
$I_{S(off)}$	Off-state switch leakage current	V_I = V_{CC} and V_O = GND, or V_I = GND and V_O = V_{CC}, $V_{INH} = V_{IH}$, (see Figure 2)	5.5 V		±1	µA
$I_{S(on)}$	On-state switch leakage current	V_I = V_{CC} or GND, $V_{INH} = V_{IL}$, (see Figure 3)	5.5 V		±1	µA
I_{CC}	Supply current	V_I = V_{CC} or GND	5.5 V		20	µA

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V $\pm$ 0.3 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Y	Y or COM	C_L = 50 pF, (see Figure 4)		12	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Y	C_L = 50 pF, (see Figure 5)		25	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Y	C_L = 50 pF, (see Figure 5)		25	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V $\pm$ 0.5 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Y	Y or COM	C_L = 50 pF, (see Figure 4)		8	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Y	C_L = 50 pF, (see Figure 5)		18	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Y	C_L = 50 pF, (see Figure 5)		18	ns

analog switch characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		V_{CC}	T_A = 25°C			UNIT
						MIN	TYP	MAX	
Frequency response (switch on)	COM or Y	Y or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Note 5 and Figure 6)		2.3 V		30		MHz
					3 V		35		
					4.5 V		50		
Crosstalk (between any switches)	COM or Y	Y or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Note 6 and Figure 7)		2.3 V		–45		dB
					3 V		–45		
					4.5 V		–45		
Crosstalk (control input to signal output)	INH	COM or Y	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (square wave) (see Figure 8)		2.3 V		20		mV
					3 V		35		
					4.5 V		65		
Feedthrough attenuation (switch off)	COM or Y	Y or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Note 6 and Figure 9)		2.3 V		–45		dB
					3 V		–45		
					4.5 V		–45		
Sine-wave distortion	COM or Y	Y or COM	C_L = 50 pF, R_L = 10 kΩ, f_{in} = 1 kHz (sine wave) (see Figure 10)	V_I = 2 V_{p-p}	2.3 V		0.1		%
				V_I = 2.5 V_{p-p}	3 V		0.1		
				V_I = 4 V_{p-p}	4.5 V		0.1		

NOTES: 5. Adjust f_{in} voltage to obtain 0 dBm at output. Increase f_{in} frequency until dB meter reads –3 dB.
6. Adjust f_{in} voltage to obtain 0 dBm at input.

operating characteristics, $T_A = 25°C$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	$C_L = 50$ pF, $f = 10$ MHz	11.8	pF

PARAMETER MEASUREMENT INFORMATION

$$r_{on} = \frac{V_I - V_O}{2 \times 10^{-3}} \; \Omega$$
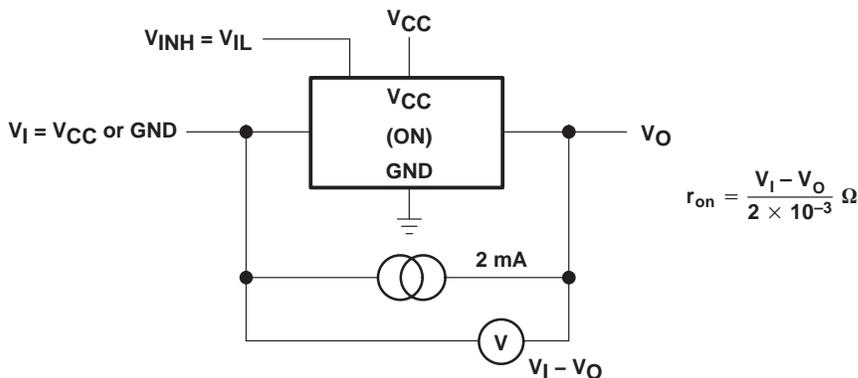
Figure 1. On-State Resistance Test Circuit

Condition 1: $V_I = 0$, $V_O = V_{CC}$
Condition 2: $V_I = V_{CC}$, $V_O = 0$
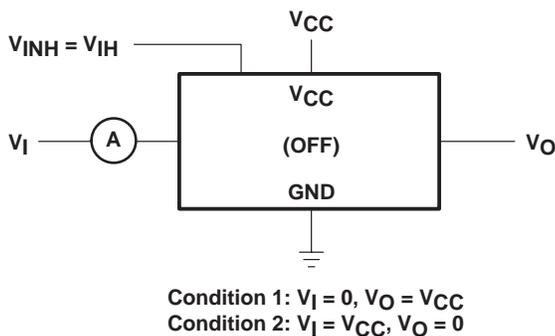
Figure 2. Off-State Switch Leakage-Current Test Circuit

$V_I = V_{CC}$ or GND
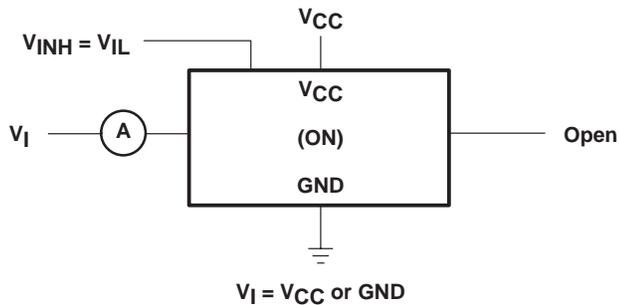
Figure 3. On-State Switch Leakage-Current Test Circuit

TEXAS
INSTRUMENTS

PARAMETER MEASUREMENT INFORMATION
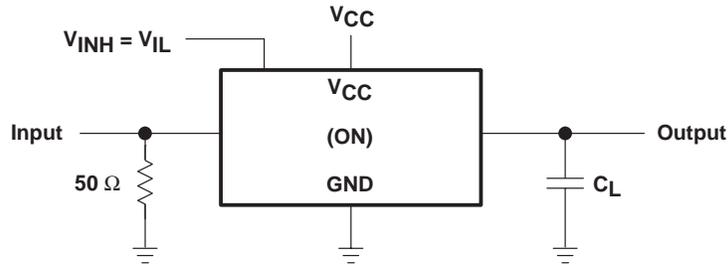
**Figure 4. Propagation Delay Time, Signal Input to Signal Output**

TEST CIRCUIT

TEST	S1	S2
t_{PLZ}/t_{PZL}	GND	V_{CC}
t_{PHZ}/t_{PZH}	V_{CC}	GND

(t_{PZL}, t_{PZH})

(t_{PLZ}, t_{PHZ})

VOLTAGE WAVEFORMS
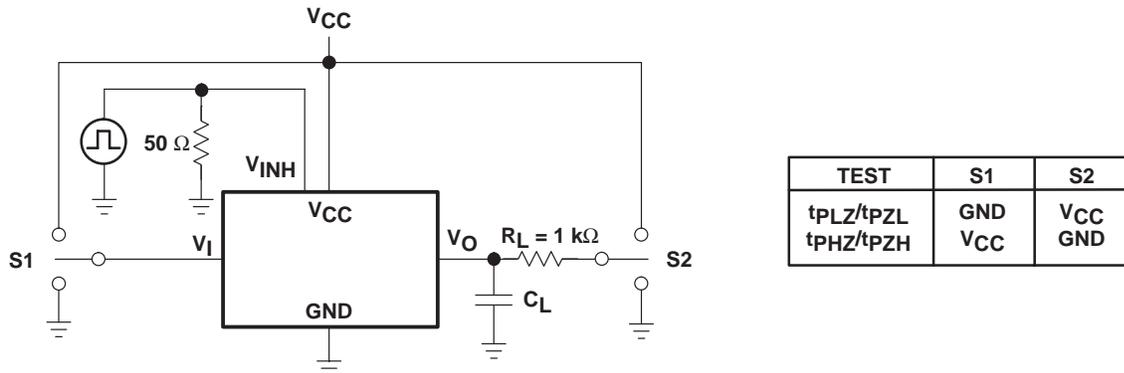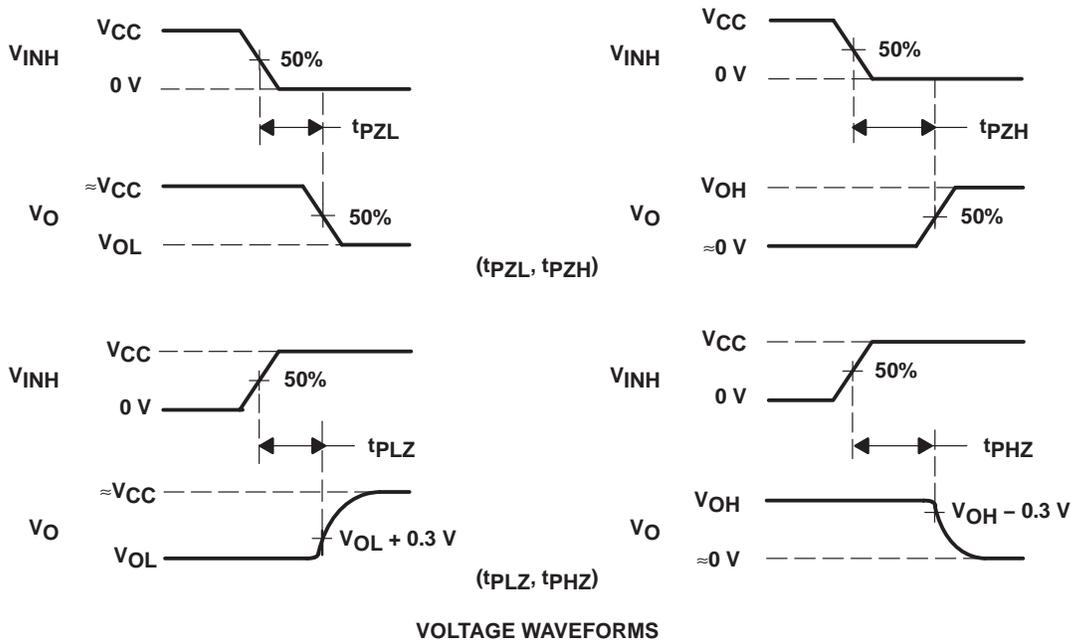
Figure 5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output

PARAMETER MEASUREMENT INFORMATION
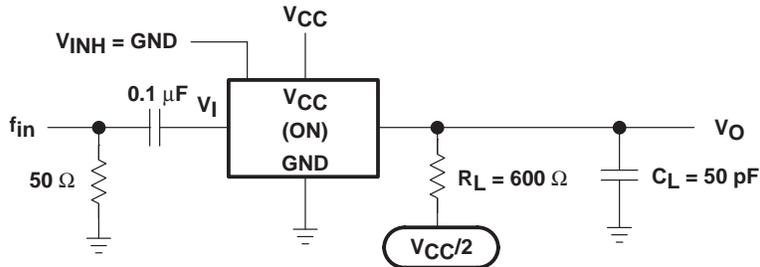
NOTE A: f_{in} is a sine wave.

Figure 6. Frequency Response (Switch On)
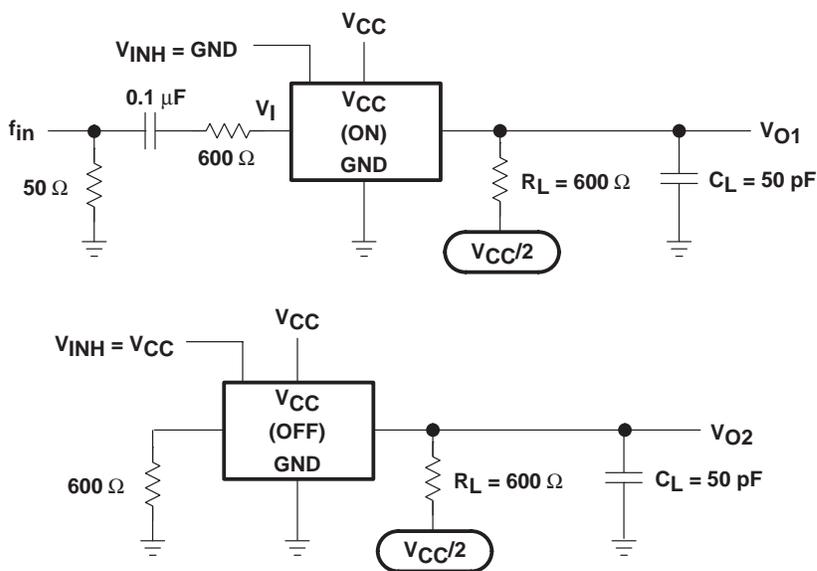
Figure 7. Crosstalk Between Any Two Switches
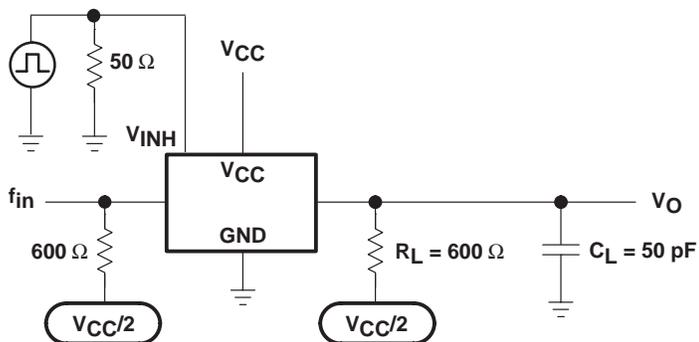
Figure 8. Crosstalk Between Control Input and Switch Output

PARAMETER MEASUREMENT INFORMATION
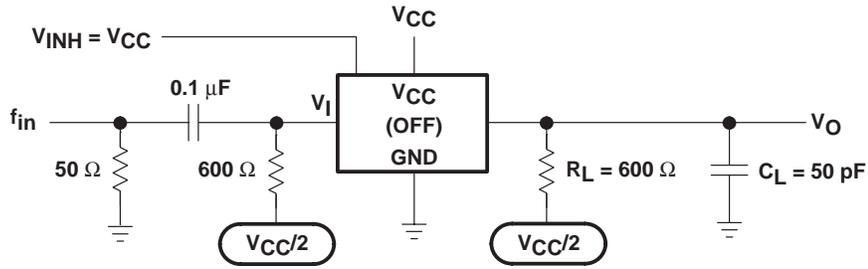
Figure 9. Feedthrough Attenuation (Switch Off)
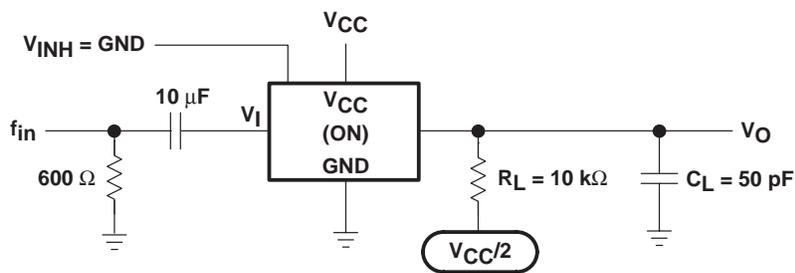
Figure 10. Sine-Wave Distortion

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV4052ATPWREP	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4052EP
SN74LV4052ATPWREP.A	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4052EP
V62/03665-01XE	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4052EP

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LV4052A-EP :

• Catalog : SN74LV4052A

● Automotive : SN74LV4052A-Q1

NOTE: Qualified Version Definitions:

　　● Catalog - TI's standard catalog product

　　● Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
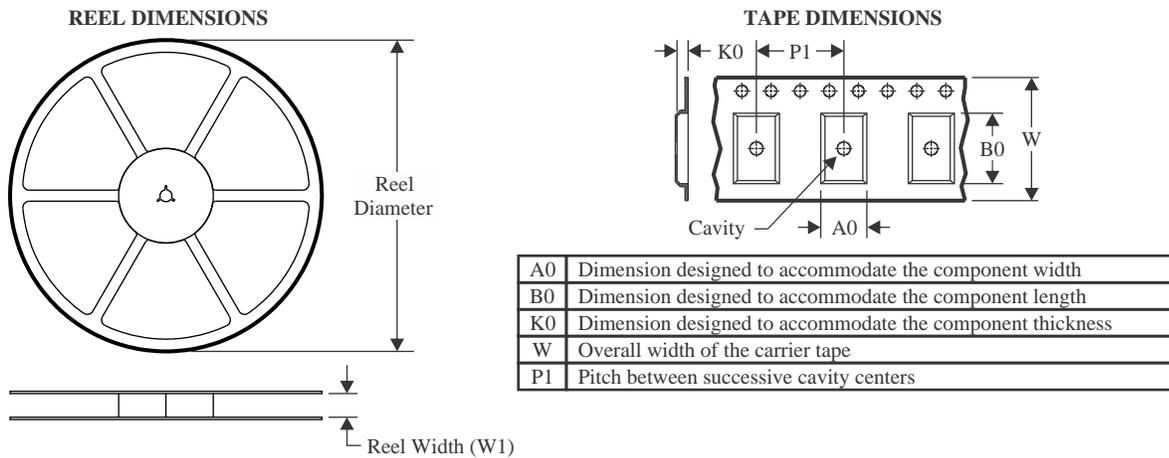
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
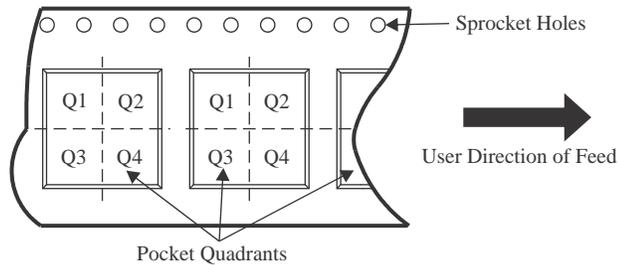
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV4052ATPWREP	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
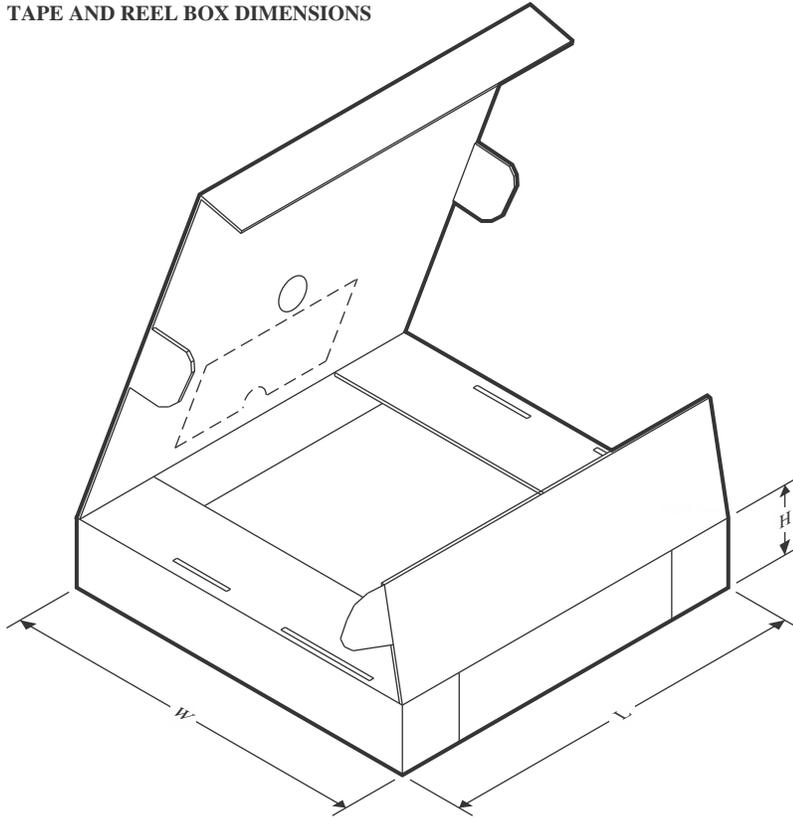
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV4052ATPWREP	TSSOP	PW	16	2000	353.0	353.0	32.0

6.6
6.2 TYP

A

PIN 1 INDEX AREA

14X 0.65

16

1

5.1
4.9
NOTE 3

2X
4.55

8

9

B

4.5
4.3
NOTE 4

16X 0.30
0.17

⊕ 0.1 Ⓜ C A B

SEATING
PLANE

C

◯ 0.1 C

4X (0°-12°)

1.2 MAX

SEE DETAIL A

(0.15) TYP

0.25
GAGE PLANE

0.15
0.05

0.75
0.50

0°-8°

DETAIL A
TYPICAL
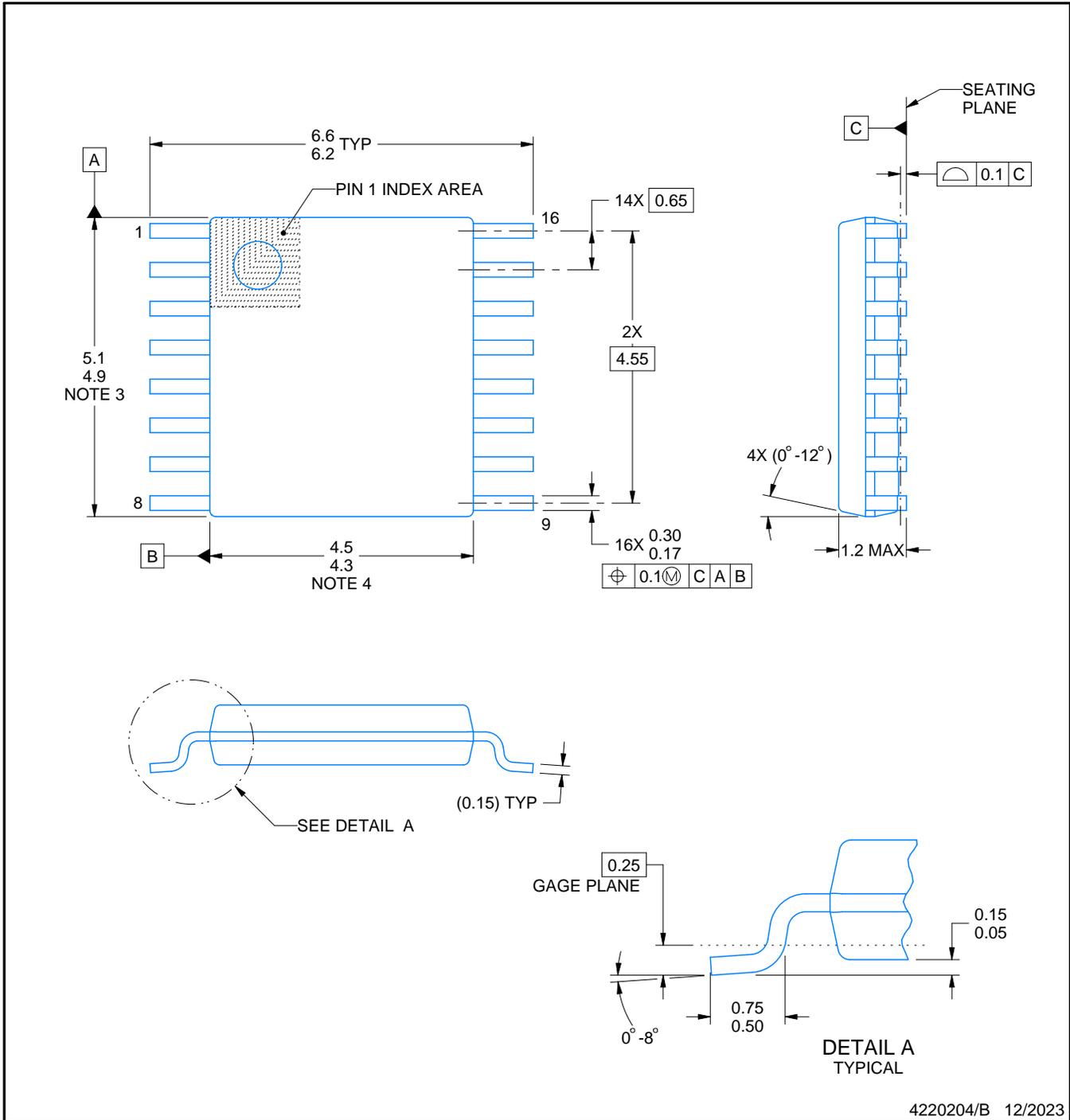
4220204/B   12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

16X (1.5)

SYMM

1

16X (0.45)

(R0.05) TYP

16

SYMM

14X (0.65)

8

9

(5.8)
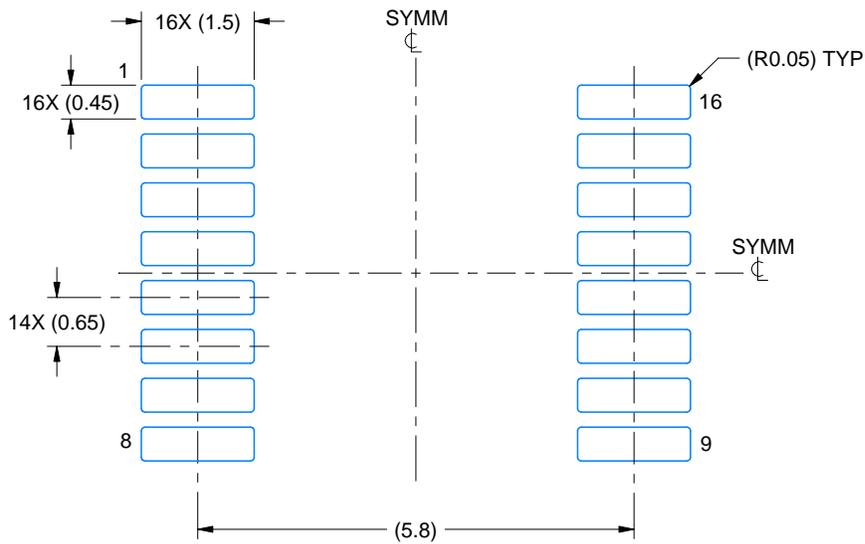
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED
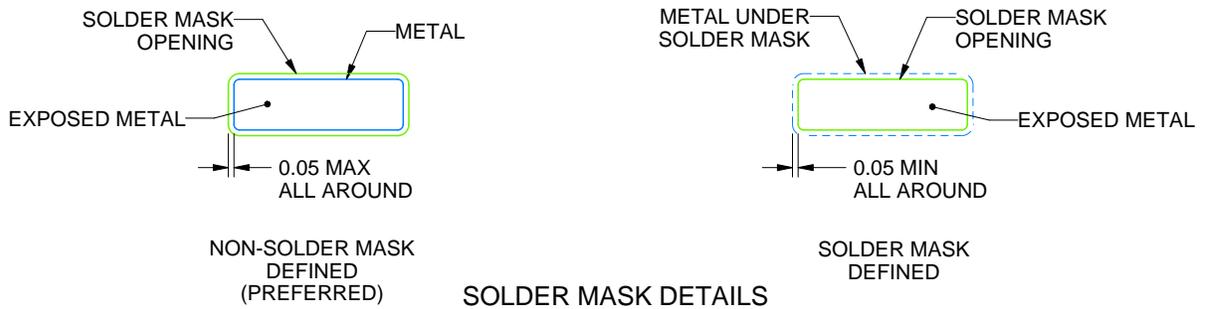
SOLDER MASK DETAILS

4220204/B   12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

16X (1.5)

SYMM

1

16X (0.45)

(R0.05) TYP

16

SYMM

14X (0.65)

8

9

(5.8)
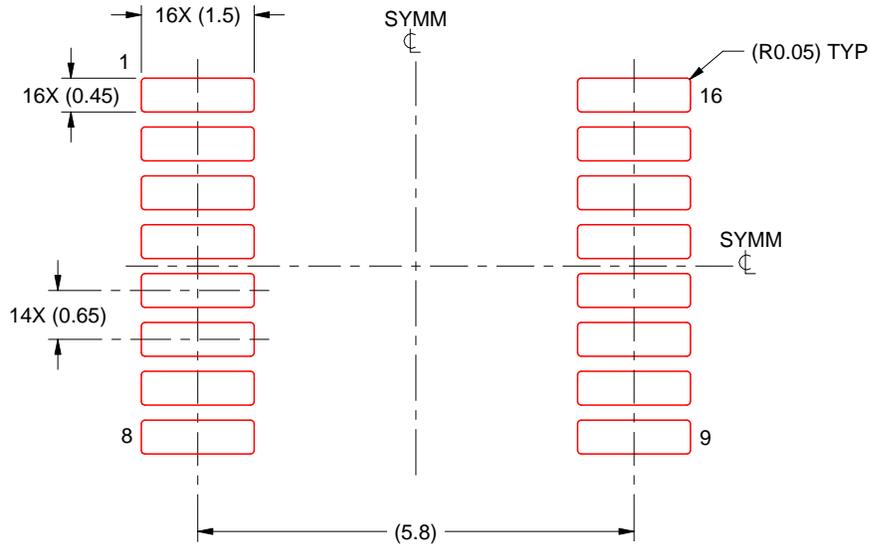
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B   12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.